

Bipolar Transistors Silicon PNP/NPN Epitaxial Type

# HN1B04FE

#### 1. Applications

• Low-Frequency Amplifiers

## 2. Q1 Features

- (1) High voltage:  $V_{CEO} = 50 \text{ V}$
- (2) High collector current:  $I_C = 150 \text{ mA (max)}$
- (3) High  $h_{FE}$ :  $h_{FE} = 120$  to 400
- (4) Excellent h<sub>FE</sub> linearity:  $h_{FE}$  ( $I_C = 0.1$  mA)/ $h_{FE}$  ( $I_C = 2$  mA) = 0.95 (typ.)

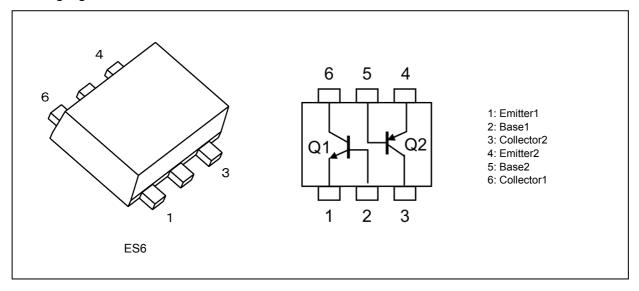
#### 3. Q2 Features

- (1) High voltage:  $V_{CEO} = -50 \text{ V}$
- (2) High collector current:  $I_C = -150 \text{ mA (max)}$
- (3) High  $h_{FE}$ :  $h_{FE} = 120$  to 400
- (4) Excellent h<sub>FE</sub> linearity:  $h_{FE}$  ( $I_{C}$  = -0.1 mA)/ $h_{FE}$  ( $I_{C}$  = -2 mA) = 0.95 (typ.)

#### 4. Q1, Q2 Common Features

(1) AEC-Q101 qualified (Please see the orderable part number list)

#### 5. Packaging and Internal Circuit





#### 6. Orderable part number

Orderable part number		AEC-Q101		Note		
HN1B04FE-Y	HN1B04FE-Y,LF			General Use		
	HN1B04FE-Y,LXGF	YES	(Note 1)	Unintended Use	(Note 1)	
	HN1B04FE-Y,LXHF	YES		Automotive Use		
HN1B04FE-GR	HN1B04FE-GR,LF	_		General Use		
	-HN1B04FEGR,LXGF	YES	(Note 1)	Unintended Use	(Note 1)	
	HN1B04FE-GR,LXHF	YES		Automotive Use		

Note 1: For more information, please contact our sales or use the inquiry form on our website.

## 7. Q1 Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	60	V
Collector-emitter voltage	$V_{CEO}$	50	
Emitter-base voltage	$V_{EBO}$	5	
Collector current	I <sub>C</sub>	150	mA
Base current	I <sub>B</sub>	30	

## 8. Q2 Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	-50	V
Collector-emitter voltage	V <sub>CEO</sub>	-50	
Emitter-base voltage	V <sub>EBO</sub>	-5	
Collector current (DC)	I <sub>C</sub>	-150	mA
Base current	I <sub>B</sub>	-30	

# 9. Q1, Q2 Common Absolute Maximum Ratings (Note) (Unless otherwise specified, T<sub>a</sub> = 25°C)

Characteristics			Rating	Unit
Collector power dissipation	(Note 1)	P <sub>C</sub>	100	mW
Junction temperature		Tj	150	°C
Storage temperature		T <sub>stg</sub>	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Total rating



## 10. Q1 Electrical Characteristics (Note) (Unless otherwise specified, Ta = 25 °C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = 60 V, I <sub>E</sub> = 0 mA	_	_	100	nA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = 5 V, I <sub>C</sub> = 0 mA	_	_	100	
DC current gain (Note)	h <sub>FE</sub>	$V_{CE}$ = 6 V, $I_C$ = 2 mA	120	_	400	_
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> = 100 mA, I <sub>B</sub> = 10 mA	_	0.1	0.25	\ \
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 1 mA	80	_	_	MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0 mA, f = 1 MHz		2	_	pF

Note:  $\,\,$   $h_{FE}$  classification Y (Y): 120 to 240, GR (G): 200 to 400  $\,$ 

() marking symbol

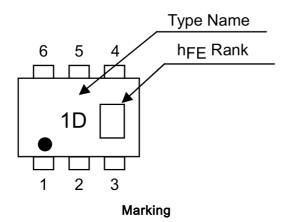
## 11. Q2 Electrical Characteristics (Note) (Unless otherwise specified, Ta = 25 °C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = -50 V, I <sub>E</sub> = 0 mA	_	_	-100	nA
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = -5 \text{ V}, I_{C} = 0 \text{ mA}$	_	_	-100	
DC current gain (Not	e) h <sub>FE</sub>	$V_{CE}$ = -6 V, $I_{C}$ = -2 mA	120	_	400	_
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> = -100 mA, I <sub>B</sub> = -10 mA	_	-0.1	-0.3	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = -10 V, I <sub>C</sub> = -1 mA	80	_	_	MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = -10 V, I <sub>E</sub> = 0 mA, f = 1 MHz	_	4	_	pF

Note:  $h_{FE}$  classification Y (Y): 120 to 240, GR (G): 200 to 400

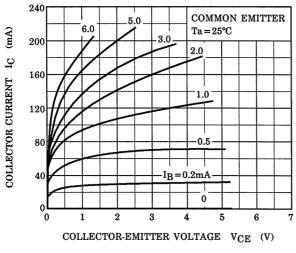
() marking symbol

#### 12. Marking





#### 13. Q1 Characteristics Curves (Note)



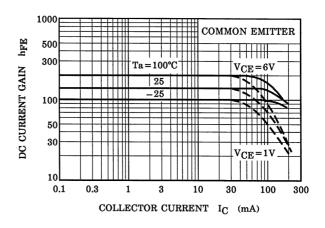


Fig. 13.1 I<sub>C</sub> - V<sub>CE</sub>

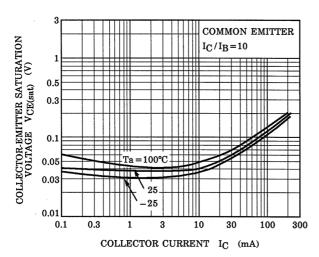


Fig. 13.2 h<sub>FE</sub> - I<sub>C</sub>

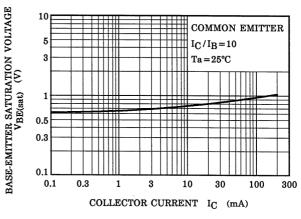


Fig. 13.3 V<sub>CE(sat)</sub> - I<sub>C</sub>

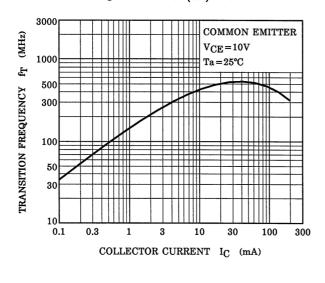


Fig. 13.4 V<sub>BE(sat)</sub> - I<sub>C</sub>

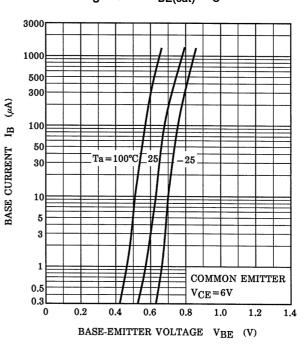
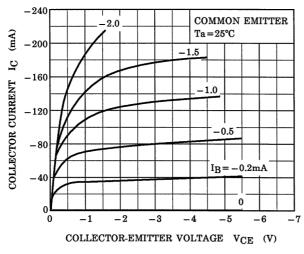


Fig. 13.5 f<sub>T</sub> - I<sub>C</sub>

Fig. 13.6 I<sub>B</sub> - V<sub>BE</sub>



#### 14. Q2 Characteristics Curves (Note)



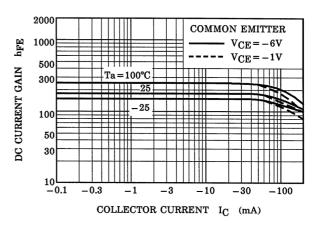


Fig. 14.1 I<sub>C</sub> - V<sub>CE</sub>

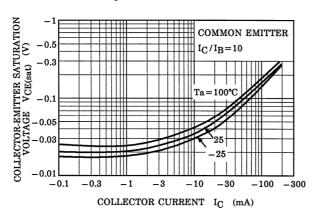


Fig. 14.2 hFE - IC

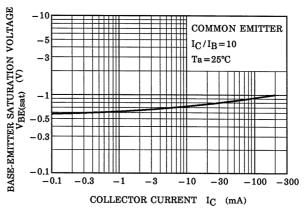


Fig. 14.3 V<sub>CE(sat)</sub> - I<sub>C</sub>

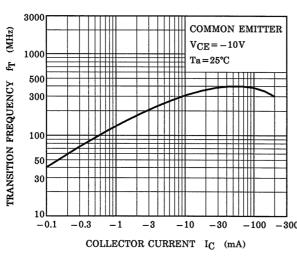


Fig. 14.4 V<sub>BE(sat)</sub> - I<sub>C</sub>

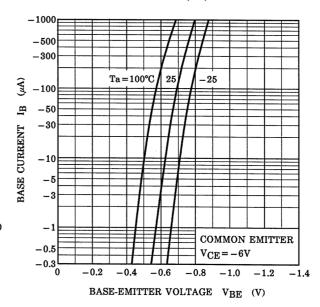


Fig. 14.5 f<sub>T</sub> - I<sub>C</sub>

Fig. 14.6 I<sub>B</sub> - V<sub>BE</sub>



## 15. Q1, Q2 Common Characteristics Curves (Note)

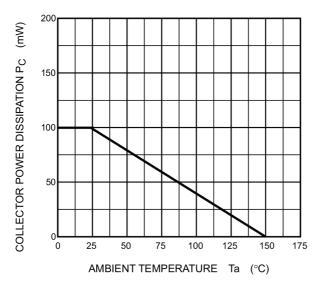


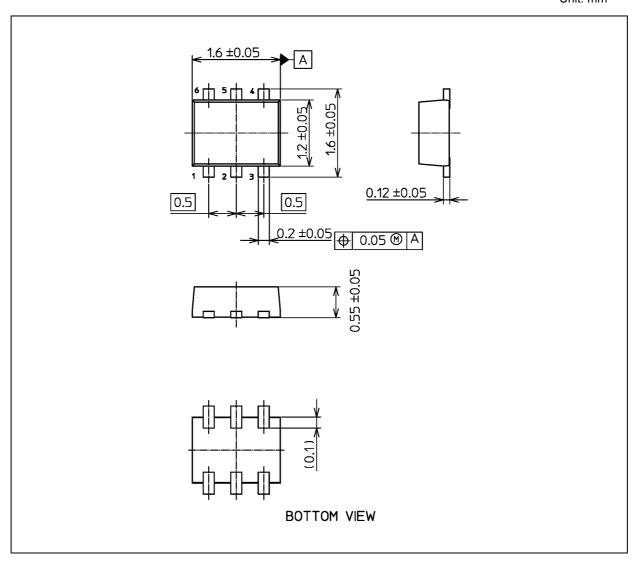
Fig. 15.1 P<sub>C</sub> (Note1) - T<sub>a</sub>

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



## **Package Dimensions**

Unit: mm



Weight: 3.0 mg (typ.)

	Package Name(s)
TOSHIBA: 1-2X1S	
Nickname: ES6	



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